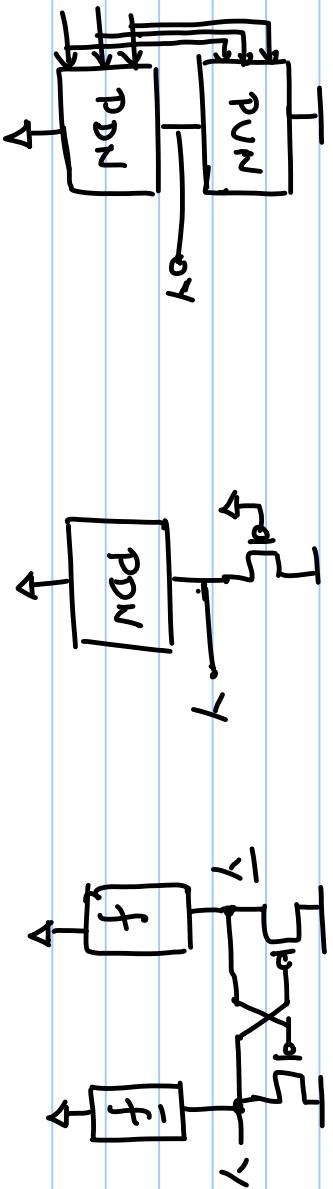


EE531

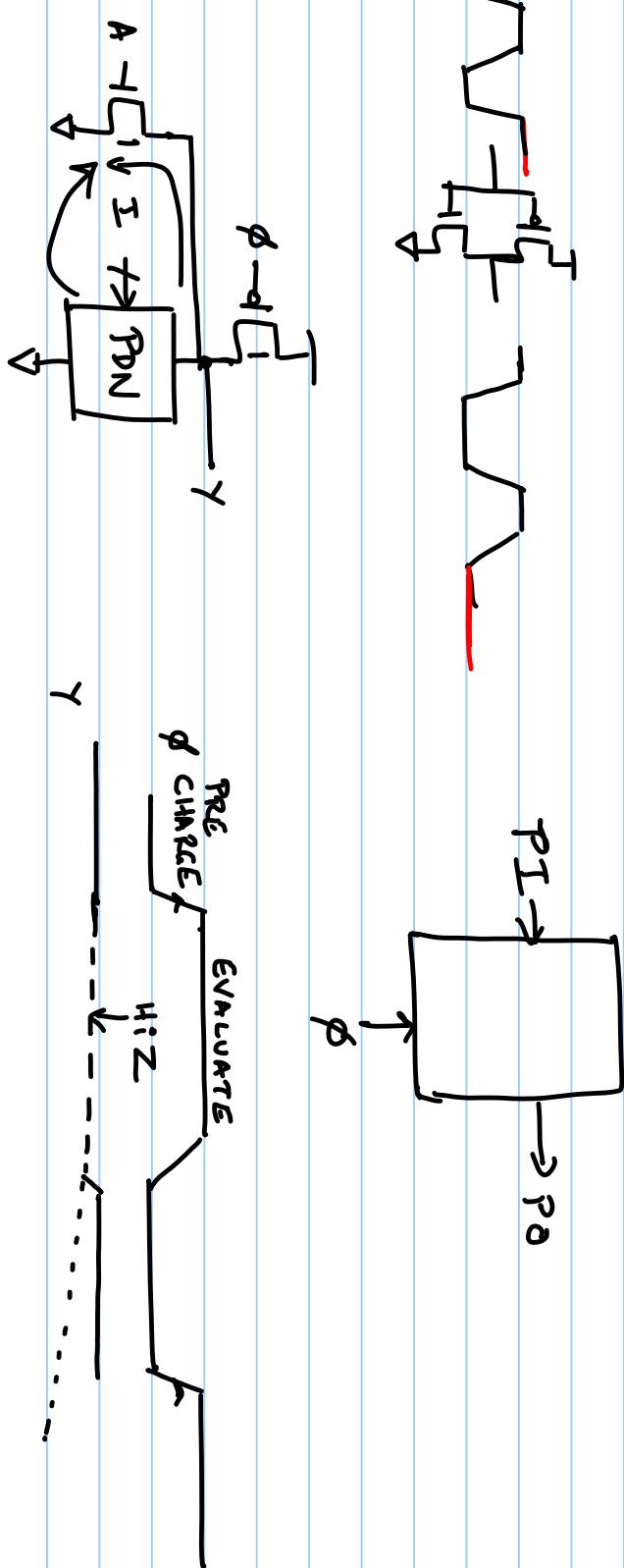
MODULE-4 - COMBINATIONAL CIRCUITS

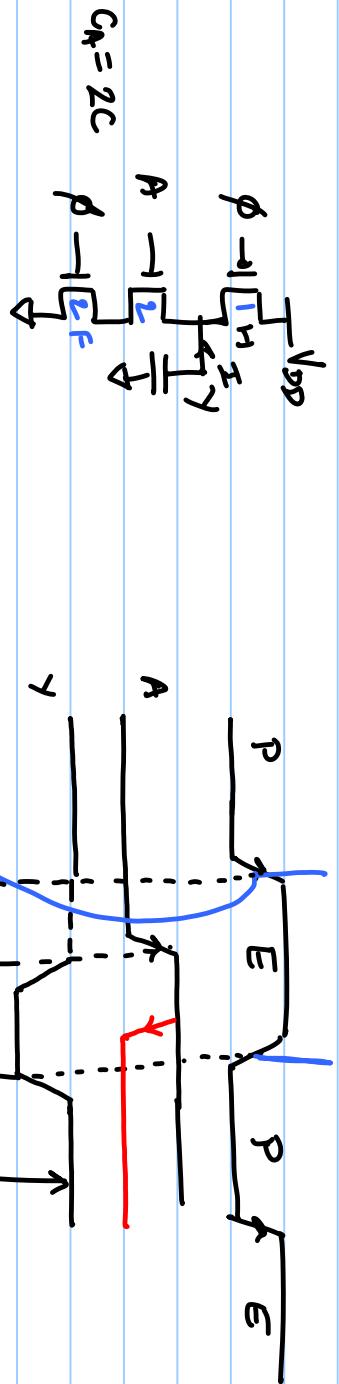
16/10/2019



STATIC CMOS	PSEUDO NMOS	C VSL
		REQUIRE AREA
VOL > 0	UP/Hn & VOL	MORE AREA
REQUIRED CKT		
STATIC CURRENT		

Dynamic Circuits.

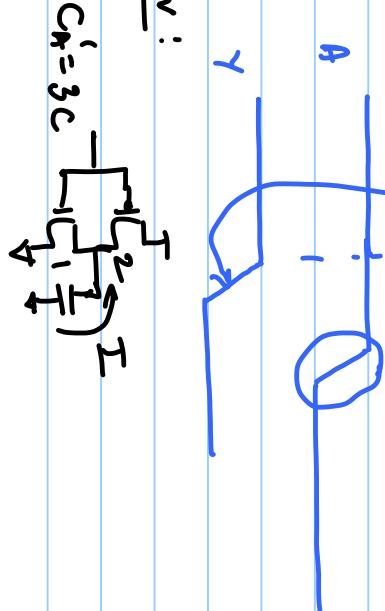




INPUT CURRENT FLOW IN
EVIL PHASE

$g_u \rightarrow$ NOT RELEVANT HERE

IF THERE
IS A FETTER
DEVICE



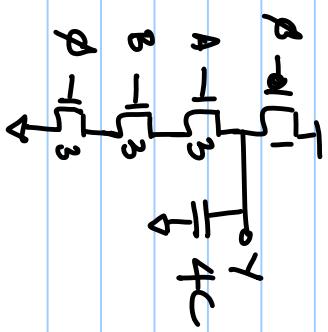
w/o Fetter Device: $g_d = \gamma/3$.

$$g_d = \gamma/3.$$

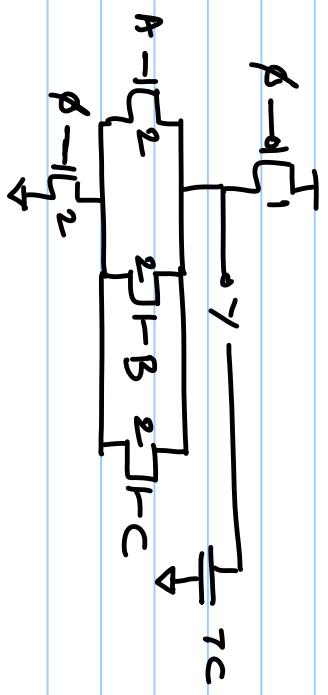
Ref Inv:

$$C_R' = 3C - \left[\frac{1}{L} \left(\frac{1}{\gamma} \right)^2 \right] \gamma$$

NAND2:



NOT2/3

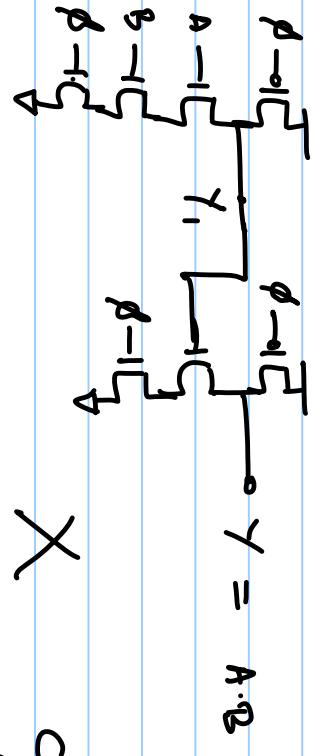


$$g_A = g_B = 1$$

$$\rho = 4/3$$

$$g_A = g_B = g_C = 2/3$$

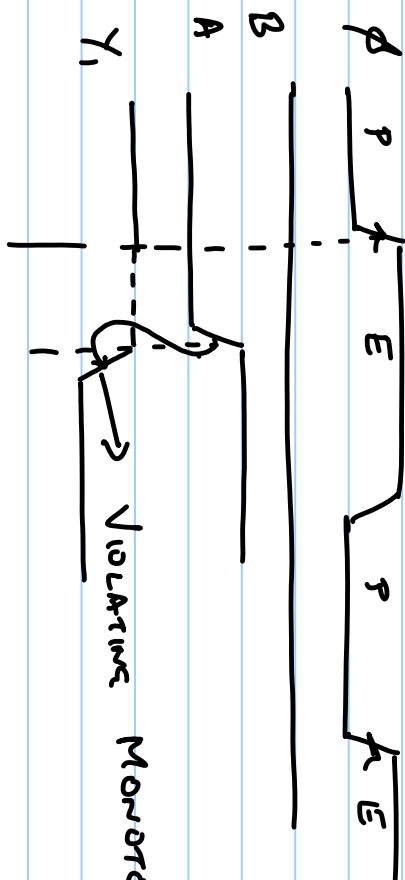
$$\rho = 7/3.$$



X

Cannot
Cascade
Gates

Dynamic



MONOTONE NON DECREASING Condition

DYNAMIC AND:

四

HISKEW - I
HISKEW - I

H. SKREW

$$A = \begin{bmatrix} 1 & 2 \\ 3 & 4 \end{bmatrix}$$

3-1

$$1 = \emptyset$$

11 -

DOMINUS LUGIE

H

101

卷之三

$$n = \sqrt{\sigma} = \sqrt{pp}$$

4 4

EVAL $\phi = 1$

PRECHARGE: $\phi = 0$

WEAK

PDN is ACTIVE
KEEPER DEVICE

